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Extremely low coercivity in Fe_3O_4 thin film grown on Mg_2TiO_4 (001)

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We report very different magnetic properties of 40 nm-thick Fe_3O_4 thin films grown on tailored spinel substrate Mg_2TiO_4 (001) and on general substrate MgO (001). The sample on Mg_2TiO_4 (001) shows a very sharp Verwey transition with narrow hysteresis of only 0.5 K and a high transition temperature up to 126 K and, in particular, an extremely small coercivity as low as around 7 Oe from the Verwey transition to room temperature. This low coercivity is close to that of the single crystal bulk but several times smaller than that of the sample on MgO (001). Our work gives a first example of the magnetic properties in Fe_3O_4 thin film having higher Verwey transition than that of the single crystal bulk, which not only greatly expands our understanding about Fe_3O_4 but also provides a very good candidate for spintronic applications with quite low energy consumption.

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I. Introduction

Magnetite (Fe₃O₄) is one of the most studied transition-metal oxides over the past several decades because of its rather unique and interesting set of magnetic and electrical properties, such as high Curie temperature ($T_{\rm C}=858$ K), relatively high saturation magnetization, small coercivity field1,2 and theoretically predicted half-metallic character.^{3,4} These properties make Fe₃O₄ very attractive for room temperature spintronic applications.⁵⁻⁹ Especially, Fe₃O₄ is a highly correlated material that undergoes a first-order metal-insulator transition (known as the Verwey transition¹⁰) at $T_V = 124$ K, but the mechanism of this transition is still unclear though tremendous amount of work has been done. However, the unique properties, which are relevant for various device applications, have been very difficult to realize in thin film form due to the existence of growth defects (such as the anti-phase boundaries (APBs)) and chemical-off stoichiometry. The inevitable presence of APBs in Fe₃O₄ thin films generally results in some unusual magnetic and transport properties, such as unsaturated magnetization in high magnetic fields, 11,12 superparamagnetic behavior for epitaxial ultrathin films, 13,14 unsaturated negative magnetoresistance, 15-24 and very low Verwey temperature and quite broadened transition. 15-19,21,22,24-26 Therefore, previous work of Fe₃O₄ thin films grown on MgO, MgAl₂O₄, SrTiO₃ or Al₂O₃ substrates in fact only reported the extrinsic magnetic and transport properties.11-26

To overcome these negative aspects, very recently, Liu et al. 27 obtained exceptionally high quality epitaxial Fe $_3O_4$ thin films

grown on tailor-made spinel Co_{2-x-y}Mn_xFe_yTiO₄ (001) substrates, which not only show the Verwey transition as sharp as the single crystal bulk but also present very high $T_{\rm V}$ up to 136.5 K. This work provides a completely new platform to further investigate the intrinsic physical properties of the magnetite.27 The Co_{2-x-v}Mn_xFe_vTiO₄ substrates, however, are magnetic, which significantly restricts the study of the magnetic properties in these high-quality Fe₃O₄ thin films. Furthermore, up to now, all the investigations on the magnetic properties of Fe₃O₄ thin films are done in the films grown on the general substrates such as MgO, $MgAl_2O_4$, Al_2O_3 , 9,11,12,15–19,21,22,24 which only show lower T_V than that of the bulk due to the existence of microstructure defects. Therefore, to study the magnetic properties in Fe₃O₄ thin film with higher $T_{\rm V}$ than that of the bulk will greatly extend our understanding about the magnetite. To experimentally achieve this goal, based on the work in ref. 27, we carefully chose and made a new nonmagnetic spinel substrate Mg2TiO4 (001) with small lattice mismatch +0.51%. We expect that the Fe₃O₄ thin film grown this substrate will present higher T_V than that of the bulk and exhibit quite different magnetic properties from that of the films grown on the general substrates.

In this work, we report very different magnetic properties of 40 nm-thick ${\rm Fe_3O_4}$ thin films grown on ${\rm Mg_2TiO_4}$ (001) and MgO (001) substrates. It is found that the sample on ${\rm Mg_2TiO_4}$ (001) displays a very sharp Verwey transition with narrow hysteresis of 0.5 K and a high $T_{\rm V}$ of 126 K, and remarkably an extremely small coercivity as low as around 7 Oe from Verwey transition to room temperature. This so low coercivity is close to that of the single crystal bulk but several times smaller than that of the sample on MgO (001), which makes ${\rm Fe_3O_4/Mg_2TiO_4}$ (001) a very good candidate for spintronic applications in quite low energy consumption.

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II. Experiments

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The 40 nm-thick Fe₃O₄ thin films were grown on Mg₂TiO₄ (001) and MgO (001) substrates by using molecular beam epitaxy (MBE) in an ultrahigh vacuum system with a background pressure of 1×10^{-10} mbar range. The substrates were annealed for 2 h at 600 $^{\circ}$ C in an oxygen pressure of 3 \times 10⁻⁷ mbar to obtain a clean and well-ordered surface structure before the deposition of Fe₃O₄. Standard samples were grown using an iron flux of 1 Å per minute, an oxygen background pressure of 1×10^{-6} mbar, and a growth temperature of 250 °C.26 To determine the structural quality and chemical states, the films were analyzed in situ by using reflection high-energy electron diffraction (RHEED), low-energy electron diffraction (LEED) and X-ray photoemission spectroscopy (XPS). The RHEED patterns were taken at 20 keV electron energy, with the beam aligned parallel to the [100] direction of the substrate. The LEED patterns were recorded

at electron energy of 88 eV. The thickness of the film was determined during growth from the oscillation period of the RHEED specular spot intensity. The XPS data were collected using 1486.6 eV photons (monochromatized Al K_{\alpha} light) in normal emission geometry and at room temperature using a Scienta R3000 electron energy analyzer. The overall energy resolution was set to about 0.3 eV. The transport and magnetic properties of the Fe₃O₄ thin films were ex situ measured with a standard four probe technique using a physical property measurement system (PPMS) and superconducting quantum interference device (SQUID), respectively. High-resolution X-ray diffraction (HR-XRD) was employed for further ex situ investigation of the structural quality and the microstructure of the thin films. The XRD measurements were performed with a high resolution PANalytical X'Pert MRD diffractometer using monochromatic Cu $K_{\alpha 1}$ radiation ($\lambda = 1.54056 \text{ Å}$).

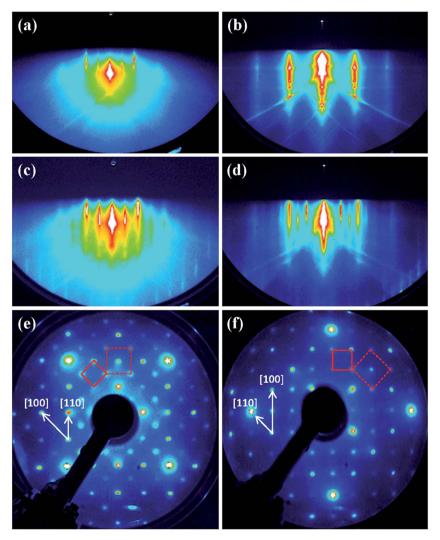


Fig. 1 RHEED and LEED electron diffraction patterns of the following: the clean substrates Mg_2TiO_4 (001) (a) and MgO (b); 40 nm-thick Fe_3O_4 thin films grown on Mg_2TiO_4 (001) (c) and (e), and on MgO (001) (d) and (f), respectively. The (1 × 1) unit cell and the $(\sqrt{2} \times \sqrt{2})R45^{\circ}$ superlattice are indicated by the red dashed square and solid square, respectively.

III. Results and discussions

Fig. 1 shows the RHEED electron diffraction patterns of clean substrates Mg₂TiO₄ (001) (a) and MgO (001) (b), the RHEED and LEED patterns of 40 nm-thick Fe₃O₄ thin films grown on Mg₂TiO₄ (001) (c and e), and on MgO (001) (d and f), respectively. The sharp RHEED streaks and the presence of Kikuchi lines (Fig. 1(c) and (d)), as well as the high contrast and sharp LEED spots (Fig. 1(e) and (f)) indicate a flat and well ordered (001) single crystalline surface structure of both samples. The characteristic $(\sqrt{2} \times \sqrt{2})R45^{\circ}$ surface reconstruction of Fe₃O₄ (001) can be observed, providing another indication for the high structural quality of the two Fe_3O_4 thin films. The (1×1) unit cell and the $(\sqrt{2} \times \sqrt{2})R45^{\circ}$ superlattice are indicated by the red dashed square and solid square, respectively (see Fig. 1(e) and (f)). 28,29 Moreover, it is found that the LEED pattern for the film on Mg₂TiO₄ (001) has 45° rotation as compared to the film on MgO (001), which should be due to the direction rotation of the substrate during its production process. Furthermore, to clarify the chemical states of the iron oxide, the thin films were in situ analyzed by XPS, as shown in Fig. 2(a)-(c). It is clear that the two samples exhibit the same wide scan spectra with binding energy from 1200 to -18 eV (Fig. 2(a)), Fe 2p core-level spectra (Fig. 2(b)) and valence band spectra (Fig. 2(c)), which demonstrates quite clean surface of the thin films and represents the

typical signatures of Fe₃O₄ thin film.^{26,27,30,31} The structural quality of the thin films was further ex situ investigated by the high-resolution X-ray diffraction (HR-XRD). As shown in the Fig. 2(d), the long range θ -2 θ XRD patterns do not present any phase other than Fe₃O₄, the (002)/(004) and (004)/(008) reflections correspond to MgO/Fe₃O₄ because of the lattice constant of Fe₃O₄ as twice as that of MgO (see the green color curve), and the (004) and (008) reflections are presented for both Mg₂TiO₄ and Fe₃O₄ for the red color curve. The two samples are in fully strained due to the small lattice mismatches. 27,32 As the lattice mismatch of Mg₂TiO₄ (+0.51%) is larger than that of MgO (+0.33%), the tensile strain and also the lattice constant a (inplane) are bigger for the former, and thus the lattice constant c (out-of-plane) of the Fe_3O_4/Mg_2TiO_4 (001) (8.343 Å) is smaller than that of the $Fe_3O_4/MgO(001)(8.367 \text{ Å})$, corresponding to the relative shift of (004) and (008) peaks to the larger angles (see the red curve).

The resistivity as a function of temperature $\rho(T)$ of 40 nm-thick Fe₃O₄ thin films grown on Mg₂TiO₄ (001) and MgO (001), and of single crystal bulk is shown in Fig. 3(a). It is found that the $\rho(T)$ curves present a clear first-order Verwey transition. The Fe₃O₄/MgO (001) sample displays a low $T_{\rm V}$ with a big hysteretic loop of about 4 K whereas the Fe₃O₄/Mg₂TiO₄ (001) sample exhibits a higher $T_{\rm V}$ (126 K) than that of the bulk with very narrow hysteresis of only 0.5 K, which demonstrates that

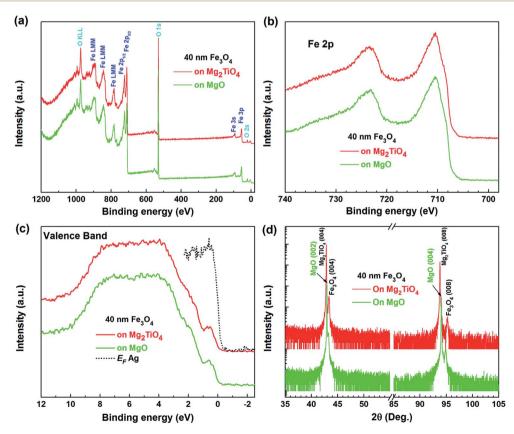


Fig. 2 XPS spectra of 40 nm-thick Fe_3O_4 thin films grown on Mg_2TiO_4 (001) and MgO (001): wide scan spectra (a), Fe 2p core-level spectra (b) and valence band spectra, as well as Ag for reference (c); (d) X-ray diffraction patterns for the Fe_3O_4 thin films on Mg_2TiO_4 (001) and MgO (001). Only the (004) and (008) reflections of Fe_3O_4 can be observed for the two samples.

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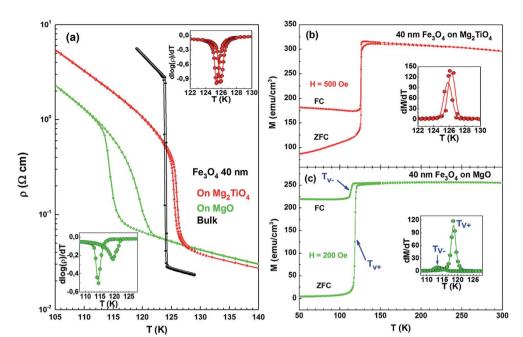


Fig. 3 Resistivity as a function of temperature for 40 nm-thick Fe₃O₄ thin films on Mg₂TiO₄ (001) and MgO (001), and of single crystal bulk Fe₃O₄ (a). Inset: temperature dependence of dlog(ρ)/dT near the T_V for the samples on Mg₂TiO₄ (001) (up) and MgO (001) (down), respectively; zero-field-cooling (ZFC) and field-cooling (FC) magnetization of the samples on Mg₂TiO₄ (001) (b) and MgO (001) (c), respectively. The dM/dT versus temperature around the T_V for the thin films on Mg₂TiO₄ (001) and MgO (001) are displayed as insets of (b) and (c), respectively.

the Fe₃O₄/Mg₂TiO₄ (001) sample has quite few microstructural defects and the tensile strain pushes the $T_{\rm V}$ over that of the bulk.²⁷ The temperature dependence of magnetization M(T) of 40 nm-thick Fe₃O₄ thin films on Mg₂TiO₄ (001) and MgO (001) are exhibited in Fig. 3(b) and (c), respectively. It is obvious that a sharp jump of magnetization takes place at Verwey transition. The T_{V-} and T_{V+} are defined respectively as the temperature of the maximum slop of $log(\rho(T))$ or M(T) curve for the cooling down and warming up temperature branches. Clearly, the T_{V+} and T_{V-} from the zero-field-cooling (ZFC) and field-cooling (FC) M(T) curves in Fig. 3(b) and (c) are consistent with that from $\rho(T)$ curves in Fig. 3(a) (see the insets of Fig. 3(a)-(c)). Furthermore, it is found that the FC curve of Fe₃O₄/Mg₂TiO₄ (001) film shows much larger magnetization change at T_{V-} than that of Fe₃O₄/ MgO (001) film (see Fig. 3(b) and (c)). Although the bulk Fe₃O₄ keeps ferrimagnetic below $T_{\rm C}\sim 860$ K, yet the easy (hard) axis changes from [111] ([100]) to [100] ([111]) with changing from cubic $Fd\bar{3}m$ to monoclinic $Cc.^{33,34}$ Usually, the bulk Fe_3O_4 exhibits a very sharp variation of magnetization at Tv under small magnetic field.35 In Fe₃O₄ thin films, however, the presence of microstructure defects can negatively affect the rotation of the magnetic axis. Therefore, the Fe₃O₄/Mg₂TiO₄ (001) film having fewer microstructure defects is more sensitive to the applied magnetic field, and the much larger magnetization change at T_{V-} can be observed.

It has been reported that the coercivity field ($H_{\rm C}$) significantly enhances with the Fe₃O₄ transforming from high-temperature cubic spinel structure to low-temperature monoclinic structure due to the abrupt increase in magnetocrystalline and magnetostriction constants. ^{35–38} The in-plane magnetic hysteresis loops at 126 K (at $T_{\rm V}$) and 127 K (just above $T_{\rm V}$) in applied

field of 50 kOe of the 40 nm ${\rm Fe_3O_4/Mg_2TiO_4}$ (001) film is shown in Fig. 4(a). It is observed that the $H_{\rm C}$ sharply decreases from 213 Oe at 126 K to only 6 Oe at 127 K (see the inset (left) of Fig. 4(a)). Remarkably, this extremely small $H_{\rm C}$ at 127 K, to our knowledge, is the smallest value in ${\rm Fe_3O_4}$ thin films so far, which is close to that of the single crystal bulk³⁶ but several times smaller than that reported in thin films grown on MgO, MgAl₂O₄, SrTiO₃ or Al₂O₃. 9,15,16,19,21,22,24,37,38 Moreover, near the $H_{\rm C}$, a clear incoherent reversal of magnetization with magnetic field for 126 K while a rapid jump of magnetization with magnetic field for 127 K are observed, see the sharp peak of ${\rm d}(M/M_{\rm S})/{\rm d}H$ at 127 K in the inset (right) of Fig. 4(a).

The in-plane $H_{\rm C}$ as a function of temperature for 40 nmthick Fe₃O₄ thin films on Mg₂TiO₄ (001) and MgO (001) are plotted in Fig. 4(c). A sharp change of $H_{\rm C}$ occurs at their Verwey transitions for the two samples, respectively. Especially, the Fe₃O₄/Mg₂TiO₄ (001) sample keeps nearly constant $H_{\rm C}$ of only about 7 Oe above its $T_{\rm V}$. As a contrast, the values of H_C are much larger for the Fe₃O₄/MgO (001) sample, ranging from 140 Oe at 130 K to 90 Oe at 300 K and still about two times bigger than that of the Fe₃O₄/Mg₂TiO₄ (001) sample at low temperatures $(T < T_{\rm V})$. Furthermore, the two samples present the perpendicular anisotropic behavior, that the inplane and out-of-plane correspond to the easy and hard axis, respectively (see Fig. 4(b)), and the anisotropic field is about 5 kOe, similar to that reported in previous work. 20,39 It has been known that the microstructural defects (such as the APBs) greatly affect the transport and magnetic properties of Fe₃O₄ thin films, the APBs were claimed to act as pining centers for the magnetic domain walls,37 thus the substantial enhancement of H_C for the Fe₃O₄/MgO (001) film should be

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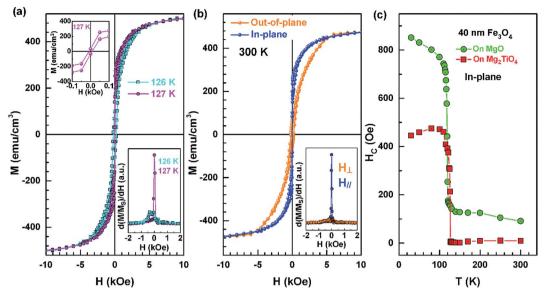


Fig. 4 (a) In-plane magnetic hysteresis loops in applied field of 50 kOe for 40 nm-thick Fe₃O₄ thin film grown on Mg₂TiO₄ (001) at 126 (at T_V) and 127 K (just above T_v). Inset: (left) magnetic hysteresis loop under small magnetic field 0.1 kOe at 127 K; (right) $d(M/M_s)/dH$ as a function of magnetic field around the H_C ; (b) in-plane and out-of-plane magnetic hysteresis loops of the sample on Mg₂TiO₄ (001) at 300 K. Inset: d(M/M_S)/ dH vs. H around the H_C ; (c) temperature dependence of H_C (in-plane) for 40 nm-thick Fe₃O₄ thin films on Mg₂TiO₄ (001) and MgO (001). A sharp change of H_C can be seen at their Verwey transitions and the values of H_C for the sample on Mg₂TiO₄ (001) are much smaller than that of the sample on MgO (001).

induced from this effect. As a result, by using a tailored spinel substrate we can obtain exceptionally high quality Fe₃O₄ thin film, with getting rid of the microstructure defects, it is the first time for us to observe the magnetic properties in Fe₃O₄ thin film having higher $T_{\rm V}$ than that of the single crystal bulk, which enlarges our understanding about the Fe₃O₄. Furthermore, this Fe₃O₄/Mg₂TiO₄ (001) thin film with extremely low coercivity will bring in quite low energy consumption in spin valves or spin tunnel junctions.

IV. Conclusion

In summary, we have studied the magnetic properties of 40 nm-thick Fe₃O₄ thin films grown on Mg₂TiO₄ (001) and on MgO (001). We found that the Fe₃O₄/Mg₂TiO₄ (001) film shows a very sharp Verwey transition with narrow hysteresis and high $T_{\rm V}$ up to 126 K, and especially an extremely small $H_{\rm C}$ as low as about 7 Oe from the Verwey transition to room temperature. This small H_C is close to that of the single crystal bulk but several times smaller than that of the films grown on general substrates. Our work not only gives a first example of the magnetic properties in Fe₃O₄ thin film having higher Verwey transition than that of the single crystal bulk but also provides a very good candidate for spintronic applications in quite low energy consumption.

Conflicts of interest

There are no conflicts to declare.

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